

MC14521B

24-Stage Frequency Divider

The MC14521B consists of a chain of 24 flip-flops with an input circuit that allows three modes of operation. The input will function as a crystal oscillator, an RC oscillator, or as an input buffer for an external oscillator. Each flip-flop divides the frequency of the previous flip-flop by two, consequently this part will count up to $2^{24} = 16,777,216$. The count advances on the negative going edge of the clock. The outputs of the last seven-stages are available for added flexibility.

- All Stages are Resettable
- Reset Disables the RC Oscillator for Low Standby Power Drain
- RC and Crystal Oscillator Outputs Are Capable of Driving External Loads
- Test Mode to Reduce Test Time
- V_{DD}' and V_{SS}' Pins Brought Out on Crystal Oscillator Inverter to Allow the Connection of External Resistors for Low-Power Operation
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load over the Rated Temperature Range.

MAXIMUM RATINGS (Voltages Referenced to V_{SS}) (Note 2.)

| Symbol | Parameter | Value | Unit |
|----------------------|---|------------------------|------|
| V_{DD} | DC Supply Voltage Range | -0.5 to +18.0 | V |
| V_{in} , V_{out} | Input or Output Voltage Range (DC or Transient) | -0.5 to $V_{DD} + 0.5$ | V |
| I_{in} , I_{out} | Input or Output Current (DC or Transient) per Pin | ± 10 | mA |
| P_D | Power Dissipation, per Package (Note 3.) | 500 | mW |
| T_A | Ambient Temperature Range | -55 to +125 | °C |
| T_{stg} | Storage Temperature Range | -65 to +150 | °C |
| T_L | Lead Temperature (8-Second Soldering) | 260 | °C |

2. Maximum Ratings are those values beyond which damage to the device may occur.

3. Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

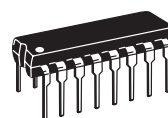
Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



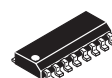
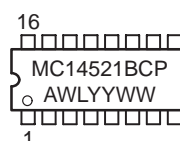
ON Semiconductor

<http://onsemi.com>

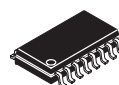
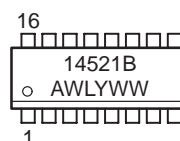
MARKING DIAGRAMS



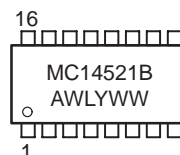
PDIP-16
P SUFFIX
CASE 648



SOIC-16
D SUFFIX
CASE 751B



SOEIAJ-16
F SUFFIX
CASE 966



A = Assembly Location
WL or L = Wafer Lot
YY or Y = Year
WW or W = Work Week

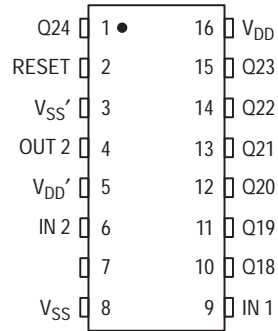
ORDERING INFORMATION

| Device | Package | Shipping |
|-------------|-----------|------------------|
| MC14521BCP | PDIP-16 | 2000/Box |
| MC14521BD | SOIC-16 | 48/Rail |
| MC14521BDR2 | SOIC-16 | 2500/Tape & Reel |
| MC14521BF | SOEIAJ-16 | See Note 1. |
| MC14521BFEL | SOEIAJ-16 | See Note 1. |
| MC14521BFR2 | SOEIAJ-16 | See Note 1. |

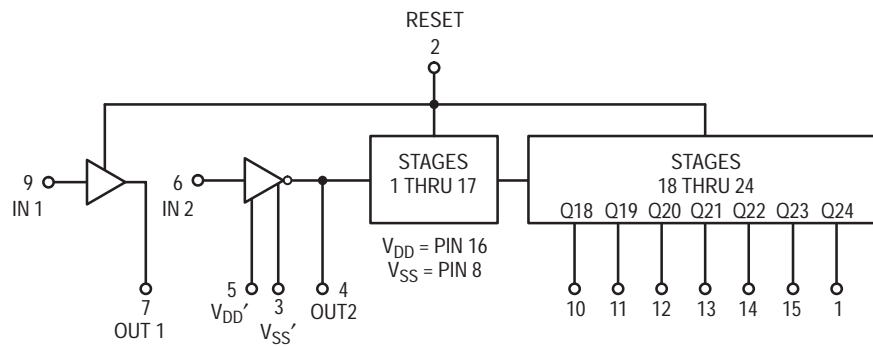
1. For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.

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PIN ASSIGNMENT



BLOCK DIAGRAM



| Output | Count Capacity |
|--------|------------------------------|
| Q18 | 2 ¹⁸ = 262,144 |
| Q19 | 2 ¹⁹ = 524,288 |
| Q20 | 2 ²⁰ = 1,048,576 |
| Q21 | 2 ²¹ = 2,097,152 |
| Q22 | 2 ²² = 4,194,304 |
| Q23 | 2 ²³ = 8,388,608 |
| Q24 | 2 ²⁴ = 16,777,216 |

MC14521B

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| Characteristic | Symbol | V _{DD} Vdc | - 55°C | | 25°C | | | 125°C | | Unit |
|---|-----------------|------------------------|--|-------|-------|-----------|-------|-------|-------|------|
| | | | Min | Max | Min | Typ (4.) | Max | Min | Max | |
| Output Voltage V _{in} = V _{DD} or 0 V _{in} = 0 or V _{DD} | V _{OL} | 5.0 | — | 0.05 | — | 0 | 0.05 | — | 0.05 | Vdc |
| | | 10 | — | 0.05 | — | 0 | 0.05 | — | 0.05 | |
| | | 15 | — | 0.05 | — | 0 | 0.05 | — | 0.05 | |
| | V _{OH} | 5.0 | 4.95 | — | 4.95 | 5.0 | — | 4.95 | — | Vdc |
| | | 10 | 9.95 | — | 9.95 | 10 | — | 9.95 | — | |
| | | 15 | 14.95 | — | 14.95 | 15 | — | 14.95 | — | |
| Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc) | V _{IL} | 5.0 | — | 1.5 | — | 2.25 | 1.5 | — | 1.5 | Vdc |
| | | 10 | — | 3.0 | — | 4.50 | 3.0 | — | 3.0 | |
| | | 15 | — | 4.0 | — | 6.75 | 4.0 | — | 4.0 | |
| | V _{IH} | 5.0 | 3.5 | — | 3.5 | 2.75 | — | 3.5 | — | Vdc |
| | | 10 | 7.0 | — | 7.0 | 5.50 | — | 7.0 | — | |
| | | 15 | 11 | — | 11 | 8.25 | — | 11 | — | |
| Output Drive Current (V _{OH} = 2.5 Vdc) Source (V _{OH} = 4.6 Vdc) Pins 4 & 7 (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) (V _{OH} = 2.5 Vdc) Source (V _{OH} = 4.6 Vdc) Pins 1, 10, (V _{OH} = 9.5 Vdc) 11, 12, 13, 14 (V _{OH} = 13.5 Vdc) and 15 (V _{OL} = 0.4 Vdc) Sink (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc) | I _{OH} | 5.0 | -1.2 | — | -1.0 | -1.7 | — | -0.7 | — | mAdc |
| | | 5.0 | -0.25 | — | -0.2 | -0.36 | — | -0.14 | — | |
| | | 10 | -0.62 | — | -0.5 | -0.9 | — | -0.35 | — | |
| | | 15 | -1.8 | — | -1.5 | -3.5 | — | -1.1 | — | |
| | | 5.0 | -3.0 | — | -2.4 | -4.2 | — | -1.7 | — | mAdc |
| | | 5.0 | -0.64 | — | -0.51 | -0.88 | — | -0.36 | — | |
| | | 10 | -1.6 | — | -1.3 | -2.25 | — | -0.9 | — | |
| | | 15 | -4.2 | — | -3.4 | -8.8 | — | -2.4 | — | |
| | I _{OL} | 5.0 | 0.64 | — | 0.51 | 0.88 | — | 0.36 | — | mAdc |
| | | 10 | 1.6 | — | 1.3 | 2.25 | — | 0.9 | — | |
| | | 15 | 4.2 | — | 3.4 | 8.8 | — | 2.4 | — | |
| Input Current | I _{in} | 15 | — | ± 0.1 | — | ± 0.00001 | ± 0.1 | — | ± 1.0 | μAdc |
| Input Capacitance (V _{in} = 0) | C _{in} | — | — | — | — | 5.0 | 7.5 | — | — | pF |
| Quiescent Current (Per Package) | I _{DD} | 5.0 | — | 5.0 | — | 0.005 | 5.0 | — | 150 | μAdc |
| | | 10 | — | 10 | — | 0.010 | 10 | — | 300 | |
| | | 15 | — | 20 | — | 0.015 | 20 | — | 600 | |
| Total Supply Current (5.) (6.) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching) | I _T | 5.0 10 15 | I _T = (0.42 μA/kHz) f + I _{DD} I _T = (0.85 μA/kHz) f + I _{DD} I _T = (1.40 μA/kHz) f + I _{DD} | | | | | | | μAdc |

4. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

5. The formulas given are for the typical characteristics only at 25°C.

6. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, V = (V_{DD} - V_{SS}) in volts, f in kHz is input frequency, and k = 0.003.

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SWITCHING CHARACTERISTICS (7.) ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

| Characteristic | Symbol | V_{DD} Vdc | Min | Typ (8.) | Max | Unit |
|--|--------------------|--|--------------------------------|--|---|---------------|
| Output Rise and Fall Time (Counter Outputs) $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ | t_{TLH}, t_{THL} | 5.0 10 15 | — — — | 100 50 40 | 200 100 80 | ns |
| Propagation Delay Time Clock to Q18 $t_{PHL}, t_{PLH} = (1.7 \text{ ns/pF}) C_L + 4415 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.66 \text{ ns/pF}) C_L + 1667 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.5 \text{ ns/pF}) C_L + 1275 \text{ ns}$ Clock to Q24 $t_{PHL}, t_{PLH} = (1.7 \text{ ns/pF}) C_L + 5915 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.66 \text{ ns/pF}) C_L + 2167 \text{ ns}$ $t_{PHL}, t_{PLH} = (0.5 \text{ ns/pF}) C_L + 1675 \text{ ns}$ | t_{PHL}, t_{PLH} | 5.0 10 15 5.0 10 15 | — — — — — — | 4.5 1.7 1.3 6.0 2.2 1.7 | 9.0 3.5 2.7 12 4.5 3.5 | μs |
| Propagation Delay Time Reset to Q_n $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 1215 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 467 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 350 \text{ ns}$ | t_{PHL} | 5.0 10 15 | — — — | 1300 500 375 | 2600 1000 750 | ns |
| Clock Pulse Width | $t_{WH(cl)}$ | 5.0 10 15 | 385 150 120 | 140 55 40 | — — — | ns |
| Clock Pulse Frequency | f_{cl} | 5.0 10 15 | — — — | 3.5 9.0 12 | 2.0 5.0 6.5 | MHz |
| Clock Rise and Fall Time | t_{TLH}, t_{THL} | 5.0 10 15 | — — — | — — — | 15 5.0 4.0 | μs |
| Reset Pulse Width | $t_{WH(R)}$ | 5.0 10 15 | 1400 600 450 | 700 300 225 | — — — | ns |
| Reset Removal Time | t_{rem} | 5.0 10 15 | 30 0 -40 | -200 -160 -110 | — — — | ns |

7. The formulas given are for the typical characteristics only at 25°C .

8. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

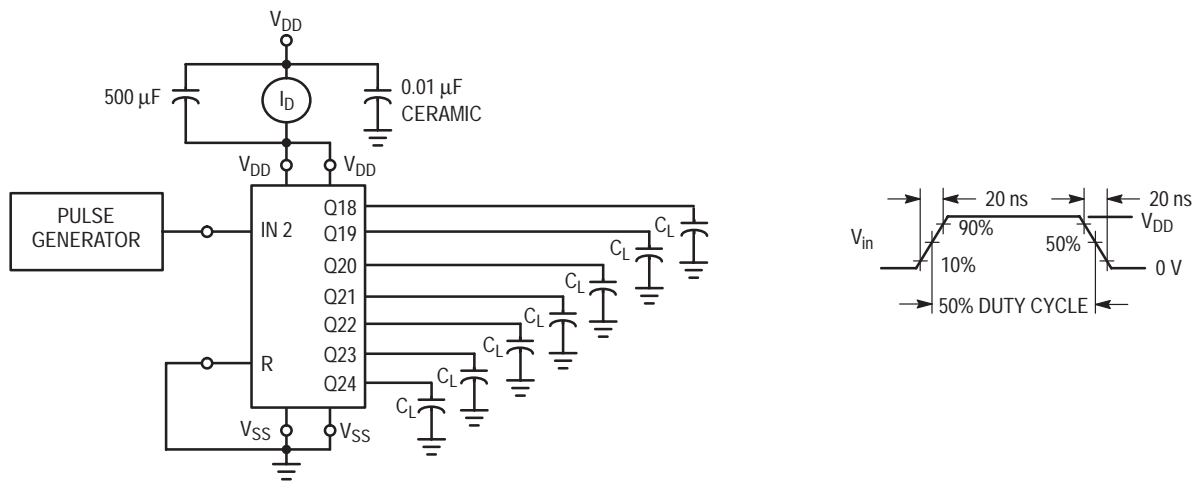


Figure 1. Power Dissipation Test Circuit and Waveform

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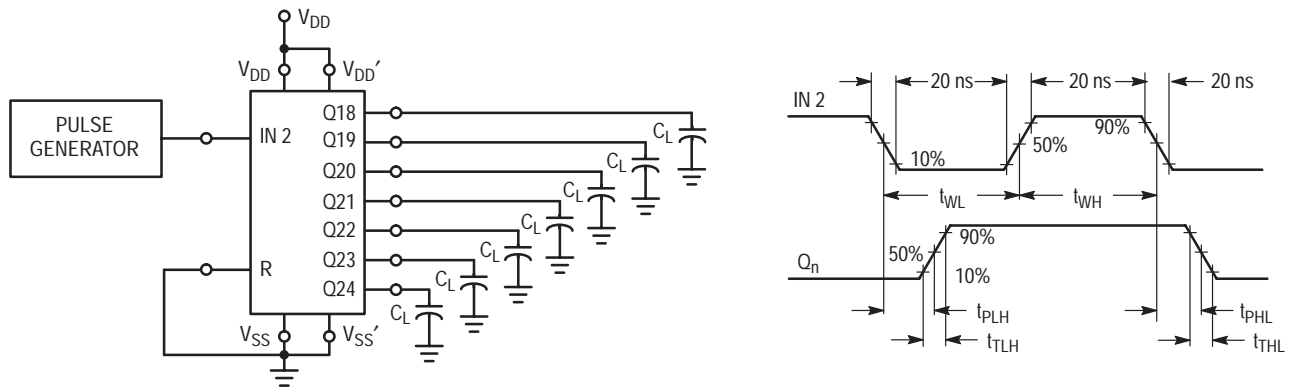
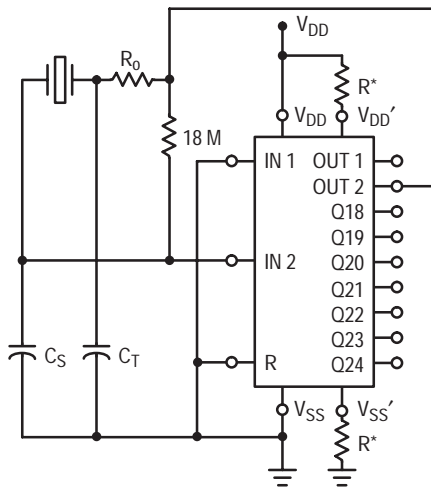


Figure 2. Switching Time Test Circuit and Waveforms



* Optional for low power operation,
 $10 \text{ k}\Omega \leq R \leq 70 \text{ k}\Omega$.

Figure 3. Crystal Oscillator Circuit

| Characteristic | 500 kHz Circuit | 50 kHz Circuit | Unit |
|---|-----------------|----------------|------------------|
| Crystal Characteristics | | | |
| Resonant Frequency | 500 | 50 | kHz |
| Equivalent Resistance, R_S | 1.0 | 6.2 | $\text{k}\Omega$ |
| External Resistor/Capacitor Values | | | |
| R_O | 47 | 750 | $\text{k}\Omega$ |
| C_T | 82 | 82 | pF |
| C_S | 20 | 20 | pF |
| Frequency Stability | | | |
| Frequency Change as a Function of V_{DD} ($T_A = 25^\circ\text{C}$) | | | |
| V_{DD} Change from 5.0 V to 10 V | + 6.0 | + 2.0 | ppm |
| V_{DD} Change from 10 V to 15 V | + 2.0 | + 2.0 | ppm |
| Frequency Change as a Function of Temperature ($V_{DD} = 10 \text{ V}$) | | | |
| T_A Change from -55°C to $+25^\circ\text{C}$ | - 4.0 | - 2.0 | ppm |
| MC14521 only | + 100 | + 120 | ppm |
| Complete Oscillator* | | | |
| T_A Change from $+25^\circ\text{C}$ to $+125^\circ\text{C}$ | - 2.0 | - 2.0 | ppm |
| MC14521 only | - 160 | - 560 | ppm |
| Complete Oscillator* | | | |

*Complete oscillator includes crystal, capacitors, and resistors.

Figure 4. Typical Data for Crystal Oscillator Circuit

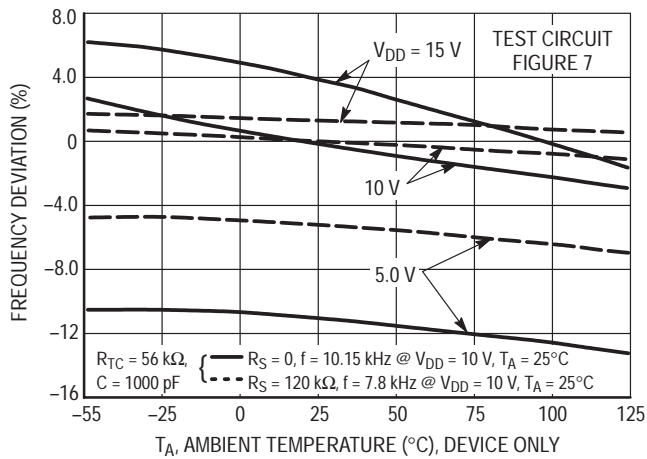


Figure 5. RC Oscillator Stability

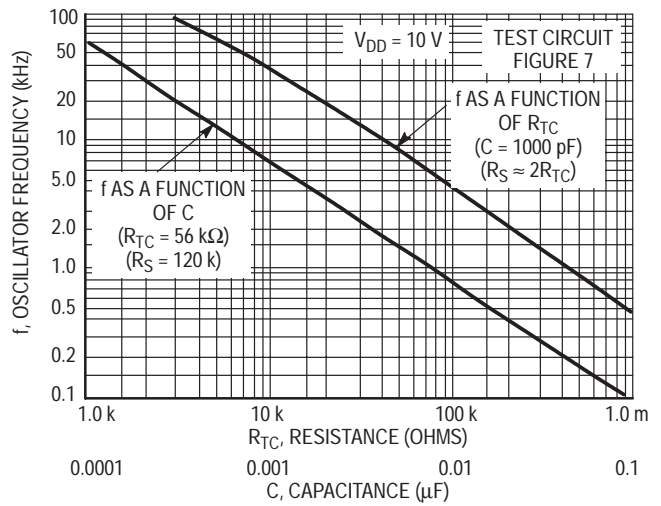


Figure 6. RC Oscillator Frequency as a Function of R_{TC} and C

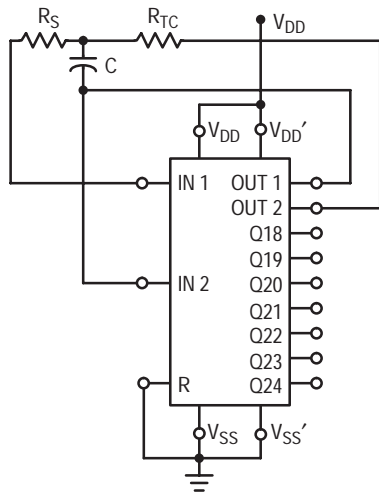


Figure 7. RC Oscillator Circuit

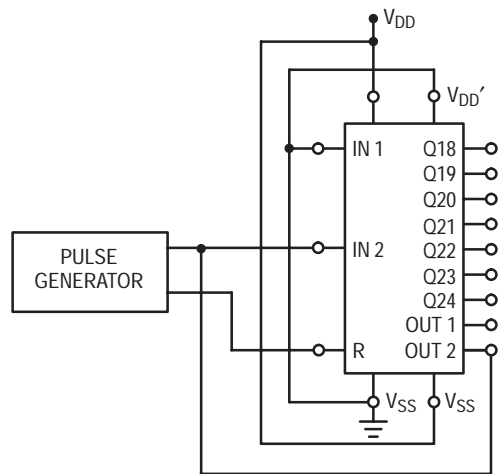


Figure 8. Functional Test Circuit

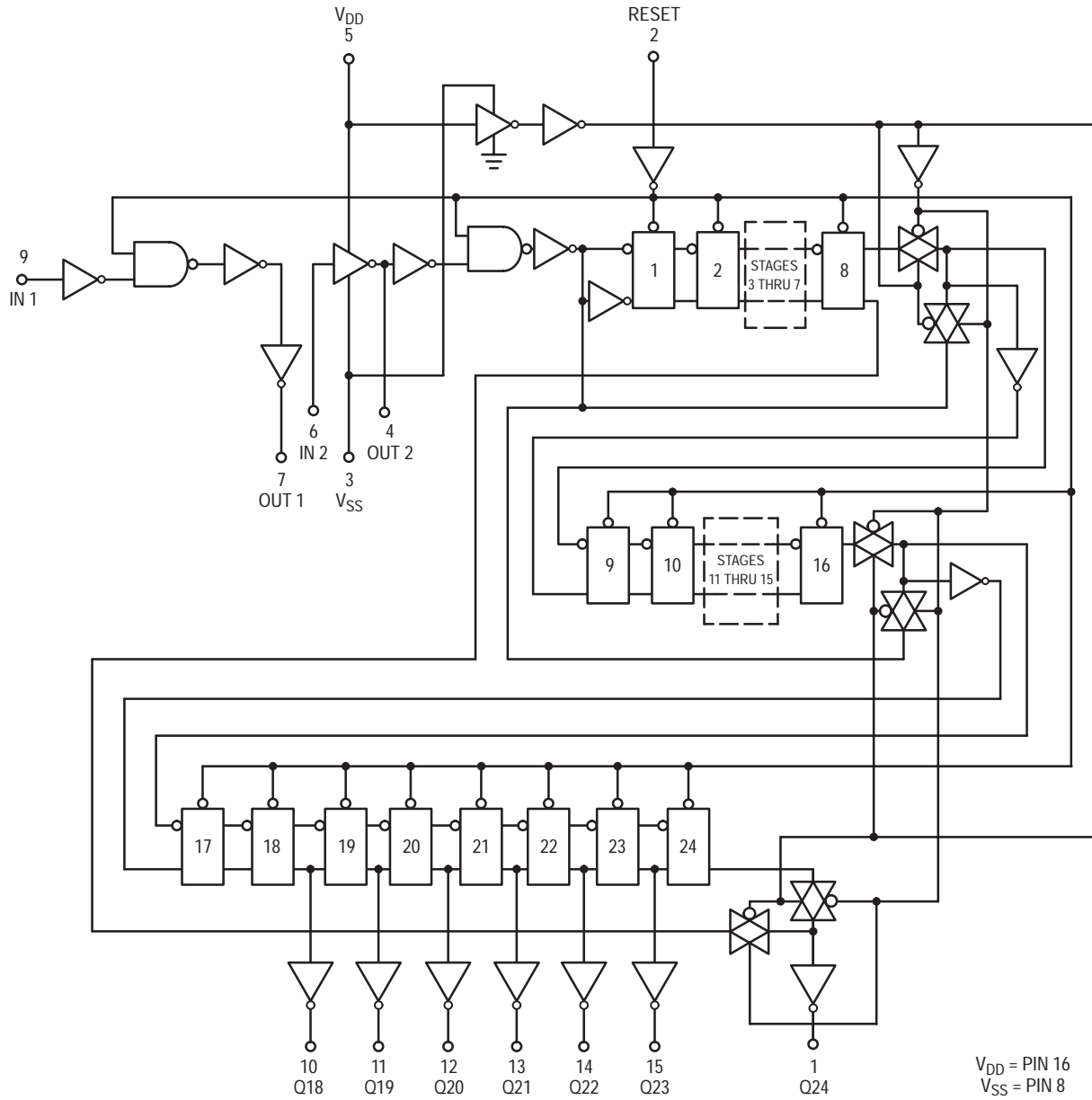
MC14521B

FUNCTIONAL TEST SEQUENCE

| <p>A test function (see Figure 8) has been included for the reduction of test time required to exercise all 24 counter stages. This test function divides the counter into three 8-stage sections, and 255 counts are loaded in each of the 8-stage sections in parallel. All flip-flops are now at a logic “1”. The counter is now returned to the normal 24-stages in series configuration. One more pulse is entered into Input 2 (In 2) which will cause the counter to ripple from an all “1” state to an all “0” state.</p> | Inputs | | Outputs | | | Comments | | | |
|---|--------|------|---------|--|--|----------------------------------|--|---|--|
| | Reset | In 2 | Out 2 | V _{SS} ’ | V _{DD} ’ | Q18 thru Q24 | Counter is in three 8-stage sections in parallel mode Counter is reset. In 2 and Out 2 are connected together | | |
| | 1 | 0 | 0 | V _{DD} Gnd | Gnd V _{DD} | 0 | First “0” to “1” transition on In 2, Out 2 node. 255 “0” to “1” transitions are clocked into this In 2, Out 2 node. | | |
| | 0 | 1 | 1 | | | | | | |
| | | 0 | 0 | | | | | | |
| | | 1 | 1 | | | | | | |
| | | — | — | | | | | | |
| | | — | — | | | | | | |
| | 1 | 1 | 1 | | | The 255th “0” to “1” transition. | | | |
| | 0 | 0 | 1 | | | Gnd | V _{DD} | 1 | Counter converted back to 24-stages in series mode. Out 2 converts back to an output. |
| | 0 | 0 | 1 | | | | | | |
| | 1 | 0 | 1 | | | | | | |
| | 1 | 0 | 1 | | | | | | |
| | 0 | 1 | 0 | Counter ripples from an all “1” state to an all “0” stage. | | | | | |

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LOGIC DIAGRAM

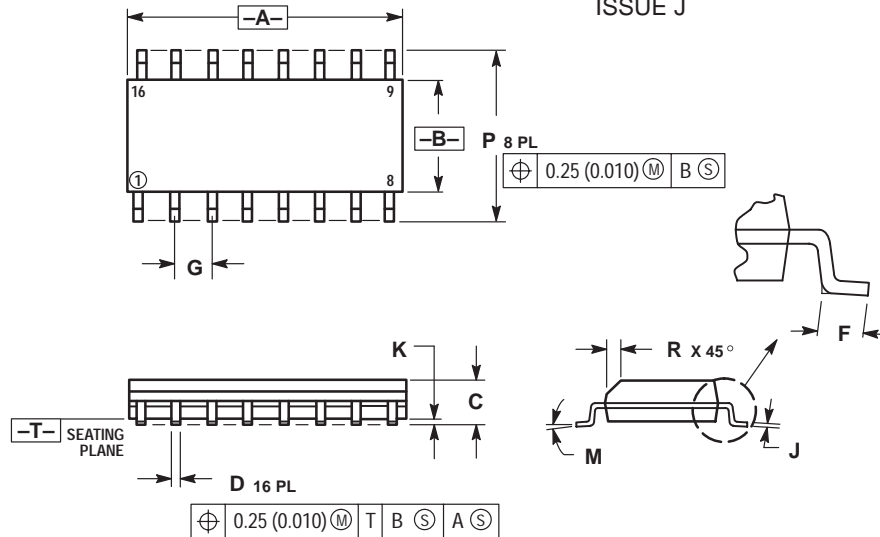


V_{DD} = PIN 16
V_{SS} = PIN 8

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PACKAGE DIMENSIONS

SOIC-16
D SUFFIX
 PLASTIC SOIC PACKAGE
 CASE 751B-05
 ISSUE J



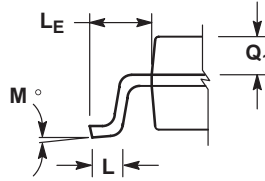
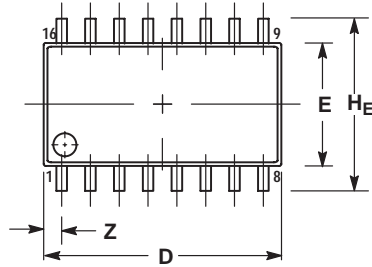
- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 9.80 | 10.00 | 0.386 | 0.393 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.054 | 0.068 |
| D | 0.35 | 0.49 | 0.014 | 0.019 |
| F | 0.40 | 1.25 | 0.016 | 0.049 |
| G | 1.27 BSC | | 0.050 BSC | |
| J | 0.19 | 0.25 | 0.008 | 0.009 |
| K | 0.10 | 0.25 | 0.004 | 0.009 |
| M | 0° | 7° | 0° | 7° |
| P | 5.80 | 6.20 | 0.229 | 0.244 |
| R | 0.25 | 0.50 | 0.010 | 0.019 |

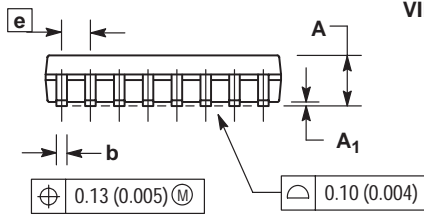
MC14521B

PACKAGE DIMENSIONS

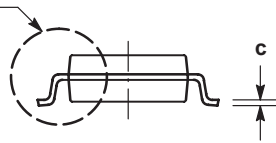
SOEIAJ-16 F SUFFIX PLASTIC EIAJ SOIC PACKAGE CASE 966-01 ISSUE O



DETAIL P




VIEW P



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

| DIM | MILLIMETERS | | INCHES | |
|----------------|-------------|-------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | — | 2.05 | — | 0.081 |
| A ₁ | 0.05 | 0.20 | 0.002 | 0.008 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| c | 0.18 | 0.27 | 0.007 | 0.011 |
| D | 9.90 | 10.50 | 0.390 | 0.413 |
| E | 5.10 | 5.45 | 0.201 | 0.215 |
| e | 1.27 BSC | | 0.050 BSC | |
| H _E | 7.40 | 8.20 | 0.291 | 0.323 |
| L | 0.50 | 0.85 | 0.020 | 0.033 |
| L _E | 1.10 | 1.50 | 0.043 | 0.059 |
| M | 0 ° | 10 ° | 0 ° | 10 ° |
| Q ₁ | 0.70 | 0.90 | 0.028 | 0.035 |
| Z | — | 0.78 | — | 0.031 |

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